



Bipolar PNP Bare Die – BTP6904

Part Description

The BTP6904 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications. NPN complement is BTN6904.

Key Parameters:

- VCBO = -40V
- VCEO = -40V
- VEBO = -5V
- hFE = 300-800 @ VCE = -5V, IC = -0.1A
- VCE(Sat) = -0.5V @ IC = -1A, IB = -100mA
- fT = 150 MHz @ VCE = -10V, IE = 0A
- COBO = 10pF @ VCB = -10V

Features

Very Low VCE(sat). Designed to provide performance equivalent to ZETEX / DIODES INC. FMMT591A

Die Size (Unawn)

660 μ m X 660 μ m, 26 Mils X 26 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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